



### OPA300, OPA2300 OPA301, OPA2301

SBOS271D - MAY 2003 - REVISED JUNE 2007

# Low-Noise, High-Speed, 16-Bit Accurate, CMOS OPERATIONAL AMPLIFIER

### **FEATURES**

- High Bandwidth: 150MHz
- 16-Bit Settling in 150ns
- Low Noise: 3nV/√Hz
- Low Distortion: 0.003%
- Low Power: 9.5mA (typ) on 5.5V
- Shutdown to 5μA
- Unity-Gain Stable
- Excellent Output Swing: (V+) – 100mV to (V–) + 100mV
- Single Supply: +2.7V to +5.5V
- Tiny Packages: MSOP and SOT23

## APPLICATIONS

- 16-Bit ADC Input Drivers
- Low-Noise Preamplifiers
- IF/RF Amplifiers
- Active Filtering

### DESCRIPTION

The OPA300 and OPA301 series high-speed, voltage-feedback, CMOS operational amplifiers are designed for 16-bit resolution systems. The OPA300/OPA301 series are unity-gain stable and feature excellent settling and harmonic distortion specifications. Low power applications benefit from low quiescent current. The OPA300 and OPA2300 feature a digital shutdown (Enable) function to provide additional power savings during idle periods. Optimized for single-supply operation, the OPA300/OPA301 series offer superior output swing and excellent common-mode range.

The OPA300 and OPA301 series op amps have 150MHz of unity-gain bandwidth, low  $3nV/\sqrt{Hz}$  voltage noise, and 0.1% settling within 30ns. Single-supply operation from 2.7V (±1.35V) to 5.5V (±2.75V) and an available shutdown function that reduces supply current to 5µA are useful for portable low-power applications. The OPA300 and OPA301 are available in SO-8 and SOT-23 packages. The OPA2300 is available in MSOP-10, and the OPA2301 is available in SO-8 and SOT-23 packages are specified over the industrial temperature range of  $-40^{\circ}$ C to  $+125^{\circ}$ C.



#### Typical Application

**A** 

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#### PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING
OPA300	SO-8	D	300A
OPA300	SOT23-6	DBV	A52
OPA301	SO-8	D	301A
OPA301	SOT23-5	DBV	AUP
OPA2300	MSOP-10	DGS	C01
OPA2301	SO-8	D	OPA2301A
OPA2301	MSOP-8	DGK	OAWM

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

#### **ABSOLUTE MAXIMUM RATINGS**

over operating free-air temperature range unless otherwise noted<sup>(1)</sup>

Power Supply V+
Signal Input Terminals <sup>(2)</sup> , Voltage 0.5V to (V+) + 0.5V
Current ±10mA
Open Short-Circuit Current <sup>(3)</sup> Continuous
Operating Temperature Range55°C to +125°C
Storage Temperature Range60°C to +150°C
Junction Temperature
ESD Ratings
Human Body Model (HBM)
Charged-Device Model (CDM)500V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) Input terminals are diode clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current limited to 10mA or less.
- (3) Short-circuit to ground; one amplifier per package.

#### **PIN ASSIGNMENTS**

#### **ELECTROSTATIC DISCHARGE SENSITIVITY**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



**ELECTRICAL CHARACTERISTICS:**  $V_S = 2.7V$  to 5.5V **Boldface** limits apply over the temperature range,  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ . All specifications at  $T_A = +25^{\circ}C$ ,  $R_L = 2k\Omega$  connected to  $V_S/2$ ,  $V_{OUT} = V_S/2$ , and  $V_{CM} = V_S/2$ , unless otherwise noted.

			0 0P			
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNITS
OFFSET VOLTAGE Input Offset Voltage	VOS	V <sub>S</sub> = 5V		1	5	mV
Drift vs. Power Supply	dV <sub>OS</sub> /dT PSRR	Vs = 2.7V to 5.5V, Vcм < (V+) −0.9V		2.5 50	200	μ <b>V/°C</b> μ <b>V/V</b>
Channel Separation, dc f = 5MHz				140 100		dB dB
INPUT VOLTAGE RANGE						
Common-Mode Voltage Range Common-Mode Rejection Ratio	V <sub>CM</sub> CMRR	(V–) – 0.2V < V <sub>CM</sub> < (V+) – 0.9V	(V–) – 0.2 66	80	(V+) – 0.9	∨ dB
INPUT BIAS CURRENT	lь			+0.1	+5	рА
Input Offset Current	IOS			±0.5	±5	pA
	00					
Differential				10 <sup>13</sup>    3		Ω    pF
Common-Mode				10 <sup>13</sup>    6		Ω    pF
NOISE						
Input Voltage Noise, f = 0.1Hz to 1MHz				40		μV <sub>PP</sub>
Input Voltage Noise Density, f > 1MHz	en			3		nV/√Hz
Input Current Noise Density, f < 1kHz	<sup>i</sup> n			1.5		fA/√Hz
Differential Gain Error		NTSC, $R_L = 150\Omega$		0.01		% 。
		N13C, KL = 13022		0.1		
Open Loop Veltage Gain	<b>A</b> ex	1/2 = 51/10 = 2k0 = 0.11/10 = 1.01/10	05	106		dB
Over Temperature	AOL	$V_{\rm S} = 5V, R_{\rm L} = 2k_{\rm S}, 0.1V < V_{\rm O} < 4.9V$	90	100		dB
		$V_{S} = 5V, R_{L} = 100\Omega, 0.5V < V_{O} < 4.5V$	95	106		dB
Over Temperature		$V_{\rm S} = 5V, R_{\rm I} = 100\Omega, 0.5V < V_{\rm O} < 4.5V$	90			dB
OUTPUT			-			
Voltage Output Swing from Rail		R <sub>L</sub> = 2kΩ, A <sub>OL</sub> > 95dB R <sub>L</sub> = 100Ω, A <sub>OL</sub> > 95dB		75 300	100 500	mV mV
Short-Circuit Current	ISC			70		mA
Open-Loop Output Impedance	RO	$I_{O} = 0, f = 1MHz$		20		Ω
Capacitive Load Drive	CLOAD		See Ty	pical Charact	eristics	
FREQUENCY RESPONSE	0.514					
Gain-Bandwidth Product	GBW	0 14		150		MHZ
Siew Rate	SK	G = +1		80		v/μs
0.1%	<sup>i</sup> S	VS = 3V, 2V Step, $G = +1$		30		ns
Overload Recovery Time		Gain = -1		30		ns
Total Harmonic Distortion + Noise	THD+N	$V_{S} = 5V, V_{O} = 3V_{PP}, G = +1, f = 1kHz$		0.003		%
POWER SUPPLY			1			
Specified Voltage Range	٧ <sub>S</sub>		2.7		5.5	V
Operating Voltage Range				2.7 to 5.5		V
Quiescent Current (per amplifier)	lQ	$I_{O} = 0$		9.5	12	mA
Over Temperature					13	mA
SHUTDOWN				10		
<sup>I</sup> OFF				40		ns
VN V. (shutdown)			$(V_{-}) = 0.2$	э	(\/_) ± 0.8	μs V
Vu (amplifier is active)			$(V_{-}) = 0.2$ $(V_{-}) + 2.5$		$(V_{+}) + 0.0$	v
IOSD (per amplifier)			. , . 2.0	3	10	μÂ
TEMPERATURE RANGE				-	-	1011 T
Specified Range			-40		+125	°C
Operating Range			-55		+125	°C
Storage Range			-60		+150	°C
Thermal Resistance	$\theta_{JA}$					°C/W
SO-8, MSOP-8, MSOP-10				150		°C/W
SOT23-5, SOT23-6				200		°C/W



#### **TYPICAL CHARACTERISTICS**

All specifications at TA = 25°C, VS = 5V, and RL = 150 $\Omega$  connected to VS/2 unless otherwise noted.



2nd-Harmonic

2nd-Harmonic

Current Noise

100k

1M

1M

10k

10

10M

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### **TYPICAL CHARACTERISTICS (continued)**

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All specifications at  $T_A = 25^{\circ}C$ ,  $V_S = 5V$ , and  $R_L = 150\Omega$  connected to  $V_S/2$  unless otherwise noted.



10M



### **TYPICAL CHARACTERISTICS (continued)**

All specifications at TA = 25°C, VS = 5V, and RL = 150 $\Omega$  connected to VS/2 unless otherwise noted.



# OPA300, OPA2300 OPA301, OPA2301

100 120 140

1

V<sub>S</sub> = 5.5V

 $V_{S} = 5V$ 

 $V_{S} = 5.5V$ 

120 140

100

2

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### **TYPICAL CHARACTERISTICS (continued)**

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All specifications at  $T_A = 25^{\circ}$ C,  $V_S = 5$ V, and  $R_L = 150\Omega$  connected to  $V_S/2$  unless otherwise noted.



#### OPA300, OPA2300 OPA301, OPA2301



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### **TYPICAL CHARACTERISTICS (continued)**

All specifications at TA = 25°C, VS = 5V, and RL = 150 $\Omega$  connected to VS/2 unless otherwise noted.





### **TYPICAL CHARACTERISTICS (continued)**

All specifications at T<sub>A</sub> = 25°C, V<sub>S</sub> = 5V, and R<sub>L</sub> = 150 $\Omega$  connected to V<sub>S</sub>/2 unless otherwise noted.





### **APPLICATIONS INFORMATION**

The OPA300 and OPA301 series of single-supply CMOS op amps are designed to interface with high-speed 16-bit analog-to-digital converters (ADCs). Featuring wide 150MHz bandwidth, fast 150ns settling time to 16 bits, and high open loop gain, this series offers excellent performance in a small SO-8 and tiny SOT23 packages.

### THEORY OF OPERATION

The OPA300 and OPA301 series op amps use a classic two-stage topology, shown in Figure 1. The differential input pair is biased to maximize slew rate without compromising stability or bandwidth. The folded cascode adds the signal from the input pair and presents a differential signal to the class AB output stage. The class AB output stage allows rail- to-rail output swing, with high-impedance loads  $(> 2k\Omega)$ , typically 100mV from the supply rails. With  $10\Omega$ loads, a useful output swing can be achieved and still maintain high open-loop gain. See the typical characteristic Output Voltage Swing vs Output Current.



Figure 1. OPA30x Classic Two-Stage Topology

#### **OPERATING VOLTAGE**

OPA300/OPA301 series op amp parameters are fully specified from +2.7V to +5.5V. Supply voltages higher than 5.5V (absolute maximum) can cause permanent damage to the amplifier. Many specifications apply from -40°C to +125°C. Parameters that vary significantly with operating voltages or temperature are shown in the Typical Characteristics.

#### PCB LAYOUT

As with most high-speed operational amplifiers, board layout requires special attention to maximize AC and DC performance. Extensive use of ground planes, short lead lengths, and high-quality bypass capacitors will minimize leakage that can compromise signal quality. Guard rings applied with potential as near to the input pins as possible help minimize board leakage.

#### INPUT AND ESD PROTECTION

All OPA300/OPA301 series op amps' pins are staticprotected with internal ESD protection diodes tied to the supplies, as shown in Figure 2. These diodes will provide overdrive protection if the current is externally limited to 10mA, as stated in the Absolute Maximum Ratings. Any input current beyond the Absolute Maximum Ratings, or long-term operation at maximum ratings, will shorten the lifespan of the amplifier.



Figure 2. ESD Protection Diodes

#### ENABLE FUNCTION

The shutdown function of the OPA300 and OPA2300 is referenced to the negative supply voltage of the operational amplifier. A logic level HIGH enables the op amp. A valid logic HIGH is defined as 2.5V above the negative supply applied to the enable pin. A valid logic LOW is defined as < 0.8V above the negative supply pin. If dual or split power supplies are used, care should be taken to ensure logic input signals are properly referred to the negative supply voltage. If this pin is not connected to a valid high or low voltage, the internal circuitry will pull the node high and enable the part to function.

The logic input is a high-impedance CMOS input. For battery-operated applications, this feature may be used to greatly reduce the average current and extend battery life. The enable time is  $10\mu$ s; disable time is  $1\mu$ s. When disabled, the output assumes a high-impedance state. This allows the OPA300 to be operated as a gated amplifier, or to have its output multiplexed onto a common analog output bus.



#### DRIVING CAPACITIVE LOADS

When using high-speed operational amplifiers, it is extremely important to consider the effects of capacitive loading on amplifier stability. Capacitive loading will interact with the output impedance of the operational amplifier, and depending on the capacitor value, may significantly decrease the gain bandwidth, as well as introduce peaking. To reduce the effects of capacitive loading and allow for additional capacitive load drive, place a series resistor between the output and the load. This will reduce available bandwidth, but permit stable operation with capacitive loading. Figure 3 illustrates the recommended relationship between the resistor and capacitor values.



Figure 3. Recommended R<sub>S</sub> and C<sub>L</sub> Combinations

Amplifiers configured in unity gain are most susceptible to stability issues. The typical characteristic, Frequency Response vs Capacitive Load, describes the relationship between capacitive load and stability for the OPA300/OPA301 In unity series. gain. the OPA300/OPA301 series is capable of driving a few picofarads of capacitive load without compromising stability. Board level parasitic capacitance can often fall into the range of a picofarad or more, and should be minimized through good circuit-board layout practices avoid compromising the stability of to the OPA300/OPA301. For more information on detecting parasitics during testing, see the Application Note Measuring Board Parasitics in High-Speed Analog Design (SBOA094), available at the TI web site www.ti.com.

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#### DRIVING A 16-BIT ADC

The OPA300/OPA301 series feature excellent THD+noise, even at frequencies greater than 1MHz, with a 16-bit settling time of 150ns. Figure 4 shows a total single supply solution for high-speed data acquisition. The OPA300/OPA301 directly drives the ADS8401, a 1.25 mega sample per second (MSPS) 16-bit data converter. The OPA300/OPA301 is configured in an inverting gain of 1, with a 5V single supply. Results of the OPA300/OPA301 performance are summarized in Table 1.



Figure 4. The OPA30x Drives the 16-Bit ADS8401

PARAMETER	RESULTS (f = 10kHz)
THD	-99.3dB
SFDR	101.2dB
THD+N	84.2dB
SNR	84.3dB

Table 1. OPA30x Performance Results Driving a 1.25MSPS ADS8401



#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
OPA2300AIDGSR	Active	Production	VSSOP (DGS)   10	2500   LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01
OPA2300AIDGSR.A	Active	Production	VSSOP (DGS)   10	2500   LARGE T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01
OPA2300AIDGST	Active	Production	VSSOP (DGS)   10	250   SMALL T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01
OPA2300AIDGST.A	Active	Production	VSSOP (DGS)   10	250   SMALL T&R	Yes	NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	C01
OPA2301AID	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A
OPA2301AID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A
OPA2301AIDGKR	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	Call TI   Nipdauag	Level-2-260C-1 YEAR	-40 to 125	OAWM
OPA2301AIDGKR.A	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	Call TI	Level-2-260C-1 YEAR	-40 to 125	OAWM
OPA2301AIDGKT	Active	Production	VSSOP (DGK)   8	250   SMALL T&R	Yes	Call TI   Nipdauag	Level-2-260C-1 YEAR	-40 to 125	OAWM
OPA2301AIDGKT.A	Active	Production	VSSOP (DGK)   8	250   SMALL T&R	Yes	Call TI	Level-2-260C-1 YEAR	-40 to 125	OAWM
OPA2301AIDR	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A
OPA2301AIDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 2301A
OPA300AID	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 300A
OPA300AID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 300A
OPA300AIDBVR	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52
OPA300AIDBVR.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52
OPA300AIDBVT	Active	Production	SOT-23 (DBV)   6	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52
OPA300AIDBVT.A	Active	Production	SOT-23 (DBV)   6	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	A52
OPA301AID	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A
OPA301AID.A	Active	Production	SOIC (D)   8	75   TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA 301A
OPA301AIDBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP
OPA301AIDBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP
OPA301AIDBVRG4.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
OPA301AIDBVT	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP
OPA301AIDBVT.A	Active	Production	SOT-23 (DBV)   5	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	AUP
OPA301AIDR	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA
									301A
OPA301AIDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	OPA
									301A

<sup>(1)</sup> **Status:** For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2300AIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2300AIDGST	VSSOP	DGS	10	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
OPA2301AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA300AIDBVR	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA300AIDBVT	SOT-23	DBV	6	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
OPA301AIDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA301AIDBVT	SOT-23	DBV	5	250	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
OPA301AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



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#### PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2300AIDGSR	VSSOP	DGS	10	2500	356.0	356.0	35.0
OPA2300AIDGST	VSSOP	DGS	10	250	210.0	185.0	35.0
OPA2301AIDR	SOIC	D	8	2500	356.0	356.0	35.0
OPA300AIDBVR	SOT-23	DBV	6	3000	445.0	220.0	345.0
OPA300AIDBVT	SOT-23	DBV	6	250	445.0	220.0	345.0
OPA301AIDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
OPA301AIDBVT	SOT-23	DBV	5	250	180.0	180.0	18.0
OPA301AIDR	SOIC	D	8	2500	356.0	356.0	35.0

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#### TUBE



#### - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
OPA2301AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA2301AID.A	D	SOIC	8	75	506.6	8	3940	4.32
OPA300AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA300AID.A	D	SOIC	8	75	506.6	8	3940	4.32
OPA301AID	D	SOIC	8	75	506.6	8	3940	4.32
OPA301AID.A	D	SOIC	8	75	506.6	8	3940	4.32

### **DGS0010A**



#### **PACKAGE OUTLINE**

#### VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.



### DGS0010A

### **EXAMPLE BOARD LAYOUT**

#### VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



### DGS0010A

### **EXAMPLE STENCIL DESIGN**

#### VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

### D0008A



#### **PACKAGE OUTLINE**

#### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



### D0008A

### **EXAMPLE BOARD LAYOUT**

#### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



#### D0008A

### **EXAMPLE STENCIL DESIGN**

#### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



### **DBV0006A**



#### **PACKAGE OUTLINE**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



### **DBV0006A**

### **EXAMPLE BOARD LAYOUT**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



#### **DBV0006A**

### **EXAMPLE STENCIL DESIGN**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



### **DBV0005A**



#### **PACKAGE OUTLINE**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



### DBV0005A

### **EXAMPLE BOARD LAYOUT**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



#### DBV0005A

### **EXAMPLE STENCIL DESIGN**

#### SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



### **DGK0008A**



### **PACKAGE OUTLINE**

#### VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



### DGK0008A

### **EXAMPLE BOARD LAYOUT**

### <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown

on this view. It is recommended that vias under paste be filled, plugged or tented.

9. Size of metal pad may vary due to creepage requirement.



### DGK0008A

### **EXAMPLE STENCIL DESIGN**

# <sup>™</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

12. Board assembly site may have different recommendations for stencil design.



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